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Power LDMOS transistor Rev. 1 — 30 November 2017

#### **Product profile** 1.

#### 1.1 General description

360 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1805 MHz to 1880 MHz.

#### **Typical performance** Table 1.

Typical RF performance at  $T_{case}$  = 25 °C in an asymmetrical Doherty demo circuit.  $V_{DS}$  = 28 V;  $I_{Dq}$  = 650 mA (main);  $V_{GS(amp)peak}$  = 0.6 V, unless otherwise specified.

Test signal	f	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	η <sub>D</sub>	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1805 to 1880	28	56	17.0	50.5	–29.5 <mark>[1]</mark>

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1880 MHz frequency range

## 2. Pinning information

Table 2. P	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	drain2 (peak)		0.7
2	drain1 (main)		2, 7
3	gate1 (main)	5	
4	gate2 (peak)		3
5	source	[1]	
6	video decoupling (peak)		۲ <u>ــــــــــــــــــــــــــــــــــــ</u>
7	video decoupling (main)		1, 6 aaa-014884

[1] Connected to flange.

## 3. Ordering information

#### Table 3.Ordering information

Type number	Package				
	Name	Description	Version		
BLC10G18XS-360AVT	-	air cavity plastic earless flanged package; 6 leads	SOT1258-4		

## 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage		-	65	V
V <sub>GS(amp)main</sub>	main amplifier gate-source voltage		-6	+9	V
V <sub>GS(amp)peak</sub>	peak amplifier gate-source voltage		-6	+9	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1	1 -	225	°C
T <sub>case</sub>	case temperature	operating [1	l –40	+125	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

#### Table 5.Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$\label{eq:VDS} \begin{array}{l} V_{DS} = 28 \; V; \; I_{Dq} = 750 \; mA \; (main); \\ V_{GS(amp)peak} = 0,65 \; V; \; T_{case} = 80 \; ^{\circ}C \end{array}$		
		P <sub>L</sub> = 56 W	0.32	k/W
		P <sub>L</sub> = 74 W	0.29	k/W

## 6. Characteristics

Table 6.	DC characteristics	

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Main dev	vice					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	V <sub>GS</sub> = 0 V; I <sub>D</sub> = 1.2 mA	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 120 mA	1.5	2.0	2.5	V
V <sub>GSq</sub>	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 600 mA	-	2.2	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 32 V	-	-	2.8	μA
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V$	-	20	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 9 V; V <sub>DS</sub> = 0 V	-	-	280	nA
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 6.0 A	-	11.0	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I <sub>D</sub> = 4.2 A	-	120	148	mΩ
Peak dev	vice		1		1	_
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	V <sub>GS</sub> = 0 V; I <sub>D</sub> = 2.36 mA	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 236 mA	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 1500 mA	-	2.2	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 32 V	-	-	2.8	μA
I <sub>DSX</sub>	drain cut-off current	V <sub>GS</sub> = V <sub>GS(th)</sub> + 3.75 V	-	38	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 9 V; V <sub>DS</sub> = 0 V	-	-	280	nA
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 11.8 A	-	20.0	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I <sub>D</sub> = 8.26 A	-	70	88	mΩ

#### Table 7. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f_1$  = 1807.5 MHz;  $f_2$  = 1877.5 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 600 mA (main);  $V_{GS(amp)peak}$  = 0.5 V;  $T_{case}$  = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 1805 MHz to 1880 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	P <sub>L(AV)</sub> = 56 W	14.6	15.4	-	dB
RL <sub>in</sub>	input return loss	P <sub>L(AV)</sub> = 56 W	-	-12	-7	dB
η <sub>D</sub>	drain efficiency	P <sub>L(AV)</sub> = 56 W	46	50	-	%
ACPR	adjacent channel power ratio	P <sub>L(AV)</sub> = 56 W	-	-30	-26	dBc

#### Table 8. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH;  $f_1 = 1807.5$  MHz;  $f_2 = 1877.5$  MHz; RF performance at  $V_{DS} = 28$  V;  $I_{Dq} = 600$  mA (main);  $V_{GS(amp)peak} = 0.5$  V;  $T_{case} = 25$  °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 1880 MHz.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
PARO	output peak-to-average ratio	P <sub>L(AV)</sub> = 56 W	6.2	6.6	-	dB
$P_{L(M)}$	peak output power	P <sub>L(AV)</sub> = 56 W	368	410	-	W

## 7. Test information

#### 7.1 Ruggedness in Doherty operation

The BLC10G18XS-360AVT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 32 V;  $I_{Dq}$  = 600 mA;  $V_{GS(amp)peak}$  = 0.5 V; f = 1807.5 MHz;  $P_L$  = 117 W (5.5 dB OBO); 1-carrier W-CDMA, 100 % clipping.

#### 7.2 Impedance information

#### Table 9. Typical impedance of main device

Measured load-pull data of main device;  $I_{Dq}$  = 670 mA (main);  $V_{DS}$  = 28 V; pulsed CW ( $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %).

f	Z <sub>S</sub> <sup>[1]</sup>	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	η <mark>ρ [2]</mark>	G <sub>p</sub> [2]				
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)				
Maximu	Maximum power load								
1800	1.0 – j4.5	1.3 – j2.7	190	63.4	16.8				
1845	1.3 – j4.9	1.2 – j2.7	190	60.2	16.5				
1880	1.6 – j5.3	1.2 – j2.9	190	59.1	16.4				
Maximu	n drain efficiency	/ load							
1805	1.0 – j4.5	2.0 – j2.0	155	71.5	18.5				
1840	1.3 – j4.9	2.0 – j1.9	145	71.0	18.7				
1880	1.6 – j5.3	2.1 – j1.8	135	70.0	19.0				

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

[2] At 3 dB gain compression.

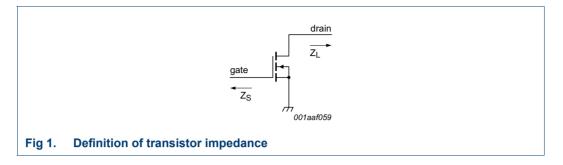
#### Table 10. Typical impedance of peak device

Measured load-pull data of peak device;  $I_{Dq}$  = 1320 mA (peak);  $V_{DS}$  = 28 V; pulsed CW ( $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %).

f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]	P <sub>L</sub> [2]	η <mark>ρ <sup>[2]</sup></mark>	G <sub>p</sub> [2]				
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)				
Maximur	Maximum power load								
1800	1.9 – j5.6	1.4 – j2.2	330	61.7	17.9				
1845	2.9 – j6.4	1.4 – j2.3	330	60.6	18.0				
1880	4.3 – j7.0	1.4 – j2.3	325	59.4	18.0				
Maximur	n drain efficiency	load							
1800	1.9 – j5.6	1.9 – j1.3	260	67.4	19.5				
1845	2.9 – j6.4	2.9 – j6.4	260	67.3	19.7				
1880	4.3 – j7.0	4.3 – j7.0	260	66.6	19.7				

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

[2] At 3 dB gain compression.



#### 7.3 Recommended impedances for Doherty design

#### Table 11. Typical impedance of main at 1 : 1 load

Measured load-pull data of main device;  $I_{Dq} = 670 \text{ mA} \text{ (main)}$ ;  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu \text{s}$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> <sup>[1]</sup>	Z <sub>L</sub> <sup>[1]</sup>	P <sub>L(3dB)</sub> [2]	η <mark>ρ <sup>[2]</sup></mark>	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1800	1.3 – j4.1	1.5 – j3.2	165	37.5	19.9
1845	1.5 – j4.2	1.5 – j2.9	170	38.0	19.9
1880	1.7 – j4.5	1.5 – j2.6	170	39.0	20.0

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

[2] At P<sub>L(AV)</sub> = 56 W.

#### Table 12. Typical impedance of main device at 1 : 2.5 load

Measured load-pull data of main device;  $I_{Dq} = 670 \text{ mA}$  (main);  $V_{DS} = 28 \text{ V}$ ; pulsed CW ( $t_p = 100 \mu s$ ;  $\delta = 10 \%$ ).

f	Z <sub>S</sub> <sup>[1]</sup>	Z <sub>L</sub> [1]	P <sub>L(3dB)</sub> [2]	ղ <b>ը <sup>[2]</sup></b>	G <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1800	1.3 – j4.1	3.3 – j1.6	100	55.9	22.6
1845	1.5 – j4.2	3.3 – j1.4	90	57.1	23.2
1880	1.7 – j4.5	3.3 – j1.1	85	57.5	23.5

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

[2] At P<sub>L(AV)</sub> = 56 W.

#### Table 13. Typical impedance of peak device at 1 : 1 load

Measured load-pull data of peak device;  $I_{Dq}$  = 1320 mA (peak);  $V_{DS}$  = 28 V; pulsed CW ( $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %).

f	Z <sub>S</sub> <sup>[1]</sup>	Z <sub>L</sub> <sup>[1]</sup>	P <sub>L(3dB)</sub> [2]	ղ <mark>ը [2]</mark>	<b>G</b> <sub>p</sub> [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
1800	2.1 – j5.0	1.5 – j2.5	275	26.0	21.5
1845	2.9 – j5.6	1.4 – j2.3	300	26.5	20.7
1880	3.9 – j6.1	1.4 – j2.1	295	27.4	21.2

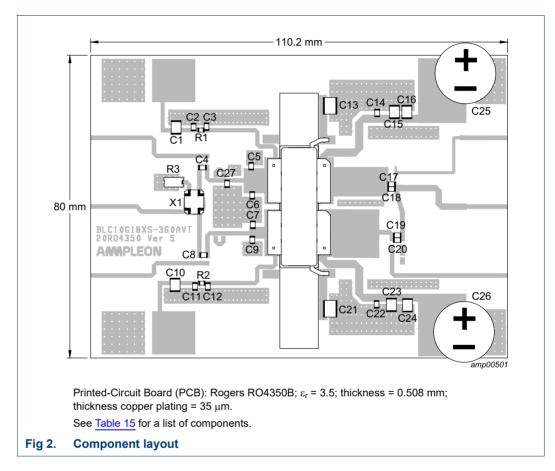
[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

[2] At P<sub>L(AV)</sub> = 56 W.

#### Table 14. Off-state impedances of peak device

f	Z <sub>off</sub>
(MHz)	(Ω)
1800	0.7 – j5.4
1845	0.9 – j6.1
1880	1.3 – j7.0

## 7.4 Test circuit



#### Table 15.List of components

See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C10, C15, C16, C23, C24	multilayer ceramic chip capacitor	4.7 μF, 100 V	SMD 1210, Murata: GRM32ER71H475KA88L
C2, C11	multilayer ceramic chip capacitor	100 nF, 50 V	SMD 0805, Murata Hi-Q
C3, C4, C8, C12, C14, C19, C20, C22	multilayer ceramic chip capacitor	10 pF	SMD 0805, Murata Hi-Q
C5	multilayer ceramic chip capacitor	2.4 pF	SMD 0805, Murata Hi-Q
C6	multilayer ceramic chip capacitor	2.7 pF	SMD 0805, Murata Hi-Q
C7	multilayer ceramic chip capacitor	2.4 pF	SMD 0805, Murata Hi-Q
C9	multilayer ceramic chip capacitor	2.2 pF	SMD 0805, Murata Hi-Q
C13, C21	multilayer ceramic chip capacitor	4.7 μF, 100 V	TDK: C5750X7R2A475KT/A

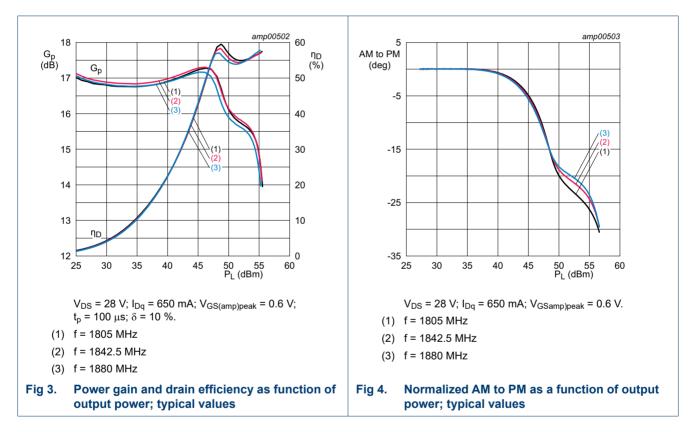
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#### Table 15. List of components ...continued

See Figure 2 for component lavout.

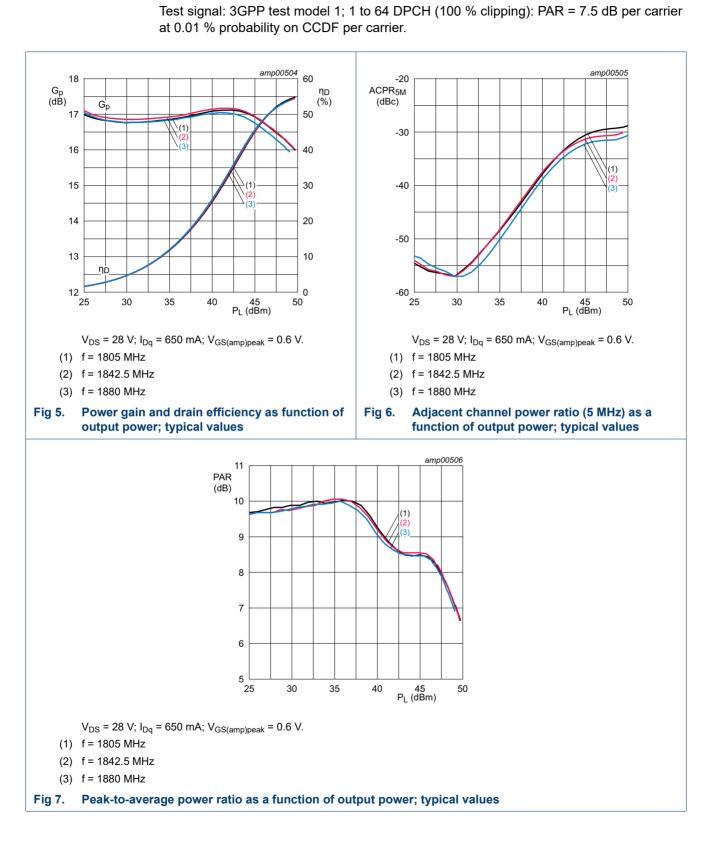
Component	Description	Value	Remarks
C17, C18	multilayer ceramic chip capacitor	2.0 pF	SMD 0805, Murata Hi-Q
C25, C26	electrolytic capacitor	470 μF, 63 V	
C27	multilayer ceramic chip capacitor	1.2 pF	SMD 0805, Murata Hi-Q
R1, R2	resistor	4.7 Ω, 1 %	SMD 0805
R3	resistor	50 Ω, 25 W	Anaren: C16A50Z4
X1	hybrid coupler	2 dB, 90°	Anaren Xinger III: X3C20F1-02

## 7.5 Graphical data



#### 7.5.1 Pulsed CW

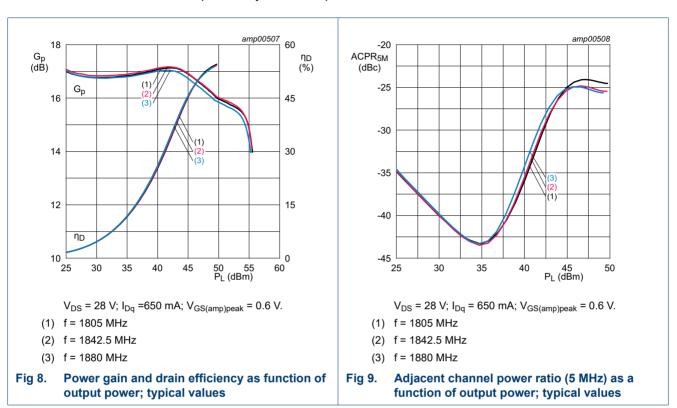
#### 7.5.2 1-Carrier W-CDMA



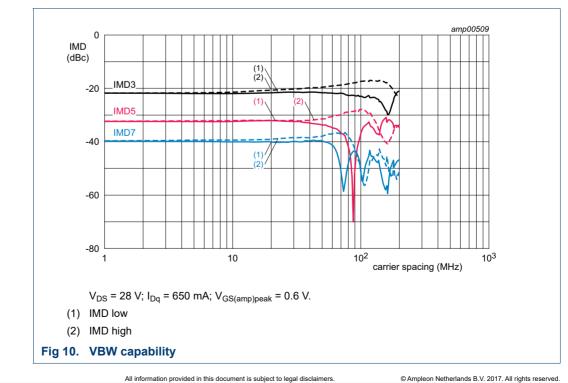
BLC10G18XS-360AVT

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#### 7.5.3 2-Carrier W-CDMA



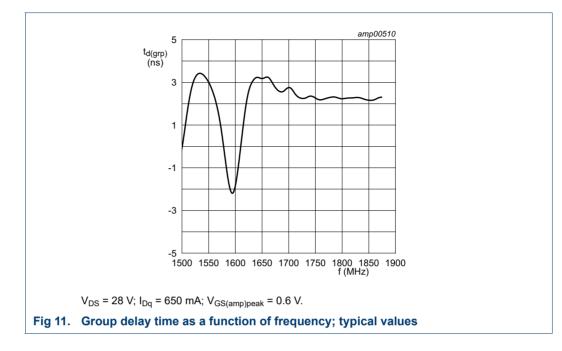
Test signal: 3GPP test model 1; 1 to 64 DPCH (100 % clipping): PAR = 7.5 dB per carrier at 0.01 % probability on CCDF per carrier.



#### 7.5.4 2-Tone VBW

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#### 7.5.5 Group delay

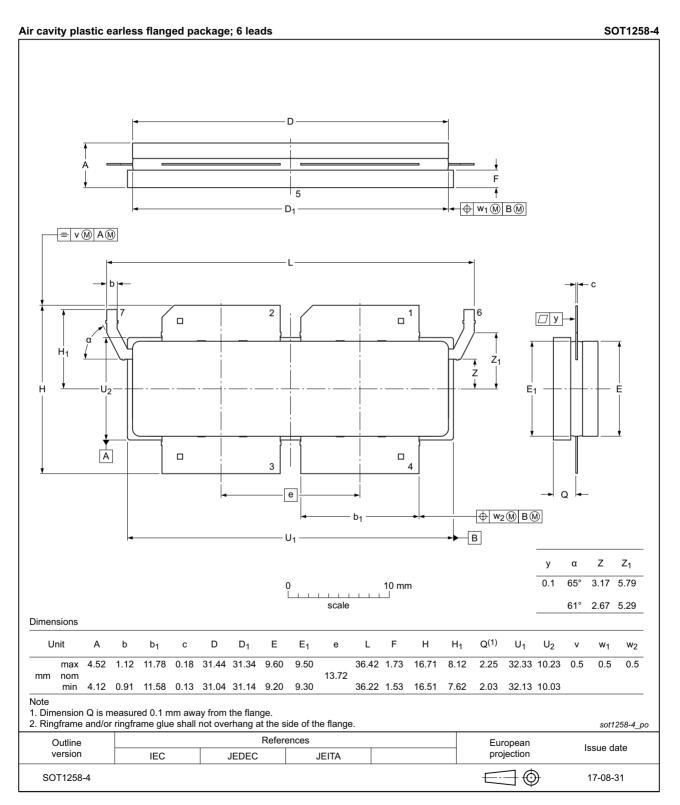


BLC10G18XS-360AVT

**Product data sheet** 

**Power LDMOS transistor** 

## 8. Package outline



#### Fig 12. Package outline SOT1258-4

BLC10G18XS-360AVT

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

#### Table 16.ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C3 [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

## **10. Abbreviations**

#### Table 17.Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back Off
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

### 11. Revision history

Table 18. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC10G18XS-360AVT v.1	20171130	Product data sheet	-	-

## 12. Legal information

### **12.1 Data sheet status**

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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